

NEW MULTIMARKET PRODUCTS QUARTERLY HIGHLIGHTS

VOLUME 2

ISSUE 2

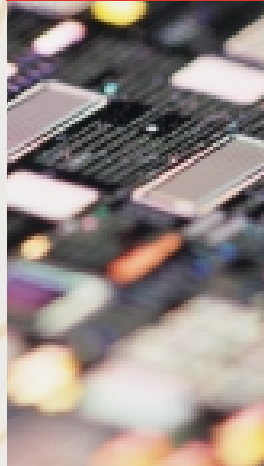
MAY 2003

Semiconductors

In this issue:

- LPC210x**
LPC2100 microcontroller family targets 16- and 32-bit systems
- PH3230S and PH8230E**
Extended range of N-Channel MOSFETs in LPAK
- BUK1M200-50SDL**
Quad low-side switch
- NE57810 and NE57811**
Advanced DDR termination regulators
- PicoGate logic**
New PicoGate logic functions in SOT505-2
- PMEM4010ND, PMEM4010PD**
Ultra low V_f (MEGA) Schottky diode and BISS transistor combination in SOT457 (SC-74)
- PMV213SN, PMV117EN, PMV60EN, PMV45EN, PMV56XN and PMV31XN**
 μ TrenchMOS 100, 30 and 20V N-Channel MOSFETs in SOT23
- Resistor-Equipped Transistors**
RET family continues to grow with 55 new options
- TDA8754**
Triple 8-bit ADC
- New Products List**

Discretes



Logic

Microcontrollers

Standard Analog

1. LPC210x

LPC2100 microcontroller family targets 16- and 32-bit systems

The LPC2100 family further expands Philips' broad microcontroller portfolio, giving customers a smooth, low-cost migration path from 8-bit and 16-bit to 32-bit. Optimized for high-performance and low-power, these devices operate at 60 MHz (54 Dhrystone MIPS) and feature 128-bit wide zero-wait state Flash, making them ideal for real-time embedded applications. Employing the ARM7TDMI-S core with Real-Time Monitor and Real-Time Trace, the new LPC2100 family ensures customers have broad industry support with software applications and tools from third party vendors (ARM, Ashling, Hitex, Keil Software, Nohau and Phytex), offering market solutions that enable rapid, low-cost, low-risk development.

Key features

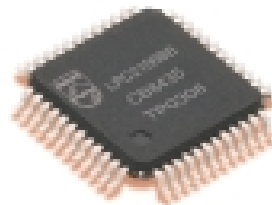
- 16 – 64 Kbytes SRAM (LPC2104, LPC2105 and LPC2106)
- 128 Kbytes 60 MHz zero-wait state Flash Program Memory
- Real-Time Clock, Watchdog, PLL, PWMs
- I^2C , SPI and 2 UARTs
- Timers and system supervisory features
- Full Embedded ICE-RT™ and ETM™ (Embedded Trace Macrocell)
- Flash In-system Programming and Updating Bootblock Software
- On-chip ARM Real-Time Monitor
- Small footprint packages: 48-pin LQFP and 48-pad MicroLeadFrame™ (HVQFN)

Key benefits

- Low power
- Large on-chip data buffer
- Best ARM interrupt handling

Key applications:

- Point-of-sales terminals
- Low power, high performance industrial control
- Data acquisition
- Security systems / access control
- Serial protocol converters
- Higher RAM content devices such as large stacks required by TCP/IP and other connectivity related applications



For more information:

<http://www.semiconductors.philips.com/pip/LPC2104BBD48.html>

PHILIPS



2. PH3230S and PH8230E

Extended range of N-Channel MOSFETs in LFPAK

Our N-channel MOSFET range of devices in the LFPAK (Loss Free PACkage) offers low thermal resistance comparable to that of larger power packages, overcoming the thermal limitations of SO8. In fact, LFPAK delivers thermal performance close to that of traditional power packages such as D-PAK and D²PAK, and features lower intrinsic inductance, making it ideal for high-frequency power switching applications.

Key features

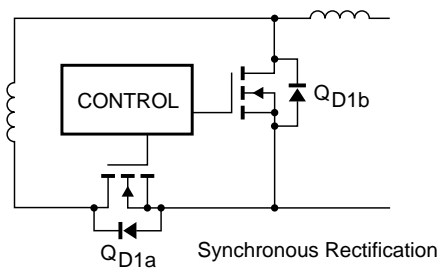
- Low intrinsic inductance – 1.1 nH (50% lower than SO8)
- 0.8 mΩ package resistance
- Low package height – 1.1 mm (40% thinner than an SO8)
- House a growing range of optimized PowerMOS devices

Key benefits

- Enables compact designs
- Faster switching in VHF circuits

Key applications

- DC/DC conversion
- Mobile equipment
- Telecommunications
- Computing



MSD837

Type Number	V _{DS} (V)	Max R _{DS(ON)} mΩ		Q _{GD} nC
		V _{GS} = 10V	V _{GS} = 4.5V	
PH3230S	30	3.2	6.5	13
PH8230E	30	8.2	13.2	5

For more information:

www.semiconductors.philips.com/pip/PH3230S.html

www.semiconductors.philips.com/pip/PH8230E.html

3. BUK1M200-50SDLD

Quad low-side switch

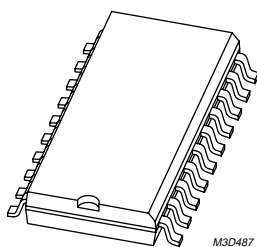
First in a new range of multi-channel TOPFET devices, the BUK1M200-50SDLD comprises four 200 m Ω low-side switches. The integration of four channels into a single 20-pin IC package enables considerable cost savings over traditional discrete solutions.

Key features

- Over-temperature protection
- Overload protection
- Current limiting
- Direct-drive capability by a standard microcontroller

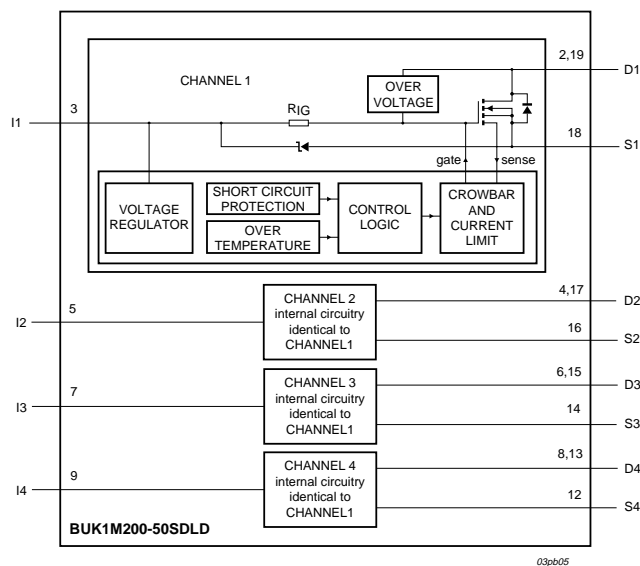
Key benefits

- Cost-effective compared to traditional discrete solutions
- Reduced board space



Key applications

- Driver for small lamps, motors and relays in many automotive systems
- Low frequency PWM
- DC switching



For more information:

www.semiconductors.philips.com/pip/BUK1M200_50SDLD.html

4. NE57810 and NE57811

Advanced DDR termination regulators

Philips' DDR (Double Data Rate) termination regulators maintain an output voltage (DDR reference bus voltage) that is one-half of the RAM supply voltage. Capable of providing up to +/- 3.5 A for sustained periods, their fast response to load changes reduces the need for output capacitors. Housed in SPAK-5 (SOT756) package, thermal robustness ensures maximum design flexibility.

Key features

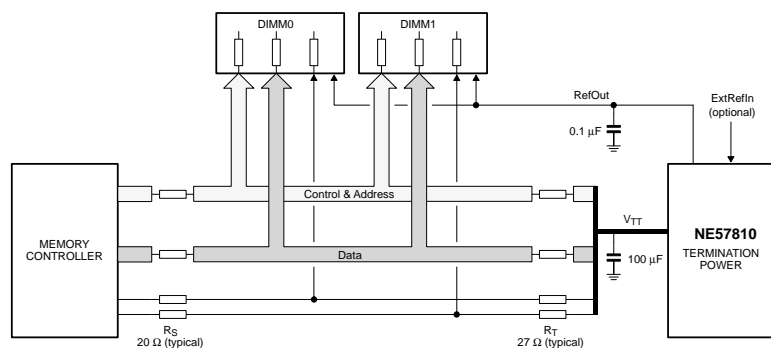
- Fast transient response time
- Over-temperature and over-current protections
- Internal divider maintains termination voltage at $\frac{1}{2}$ memory supply voltage
- Reference out for other memory and control components
- Flexibility from optional external voltage reference-in (NE57810)
- Shutdown pin (NE57811)

Key benefits

- Reduced need for external components (switching FETs, inductors, decoupling capacitors)
- Significantly reduces board space and overall system cost
- Compatible with DDR-I ($V_{DD} = 2.5\text{ V}$) and DDR-II ($V_{DD} = 1.8\text{ V}$) SDRAM systems

Key applications

- Desktop PC systems
- Workstations and servers
- Game machines
- Set-top boxes
- Embedded systems
- Digital video recorders



For more information:

www.semiconductors.philips.com/pip/NE57810S.html

www.semiconductors.philips.com/pip/NE57811S.html

5. PicoGate logic

New PicoGate logic functions in SOT505-2

Philips has expanded its logic products portfolio with the introduction of new PicoGate logic functions in the 8-pin SOT505-2 package. This extends Philips' PicoGate offering to include 5, 6 and 8-pin functions. Look out for products being released in HC, AHC and LVC technologies in the upcoming months.

Key features

- Intricate line layout patterns can be created while saving up to 85% board space
- Single-, dual-, and triple-gate functions in 5-, 6-, or 8-pin packages
- Designers can select the number of functions needed

Key benefits

- Simplifies PCB routing
- Reduced board space
- Time-to-market
- Cost-effectiveness

Key applications

- Space-critical systems
- Handheld portable devices
- SoC / ASIC fixes
- Glue logic



For more information:

www.semiconductors.philips.com/logic/products/picogate



Semiconductors

<< Contents

6. PMEM4010ND, PMEM4010PD

Ultra low V_F (MEGA) Schottky diode and BISS transistor combination in SOT457 (SC-74)

Combining an NPN or PNP transistor with low V_{CEsat} and high current capability, and an ultra low V_F Schottky rectifier diode with integrated guard ring for stress protection in a SOT457 (SC-74) small-signal package, these devices offer the highest efficiency and industry leading performance.

Key features

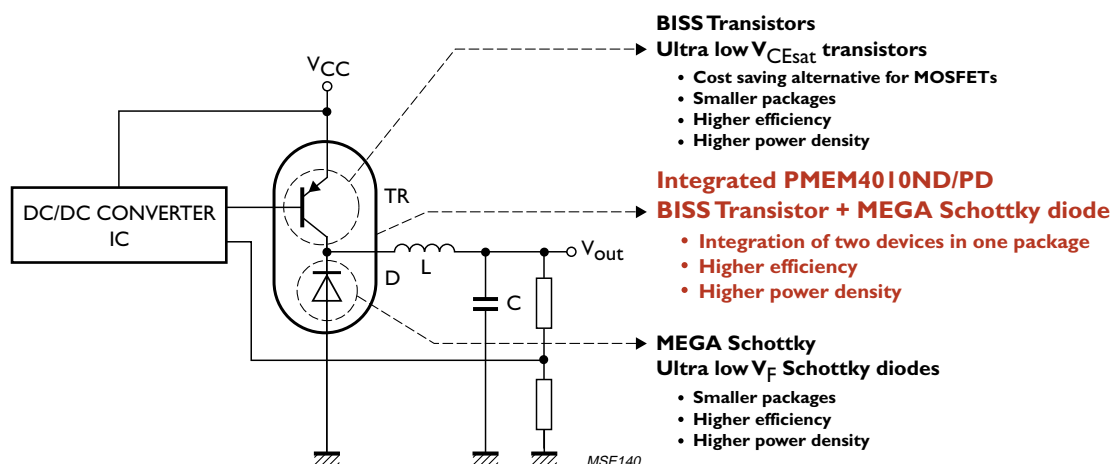
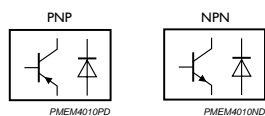
- High efficiency
- Less power losses and heat generation
- High current capability compared to size
- 600 mW total power dissipation
- 1 A current capability
- Small plastic SMD package

Key benefits

- Occupies less board space
- Reduced pick and place costs

Key applications

- Discrete DC/DC converter
- Peripheral rectifier diode combined with integrated DC/DC controllers
- Reverse polarity protection
- General purpose load drivers
- Inductive load drivers



For more information:

www.semiconductors.philips.com/pip/PMEM4010ND.html

www.semiconductors.philips.com/pip/PMEM4010PD.html



Semiconductors

<< Contents

7. PMV213SN, PMV117EN, PMV60EN, PMV45EN, PMV56XN and PMV31XN

μ TrenchMOS 100, 30 and 20 V N-Channel MOSFETs in SOT23

Continuing Philips' commitment to expand the innovative μ TrenchMOS portfolio, the new PMV series of 100, 30 and 20 V N-channel MOSFETs draws upon our core strengths of leading-edge TrenchMOS™ technology and package miniaturization to bring this family's performance benefits to the industry-standard SOT23 package.

Key features

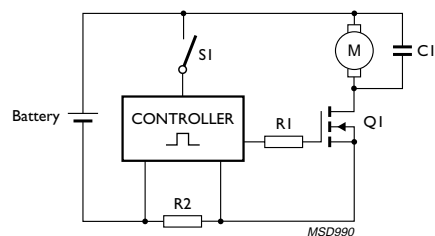
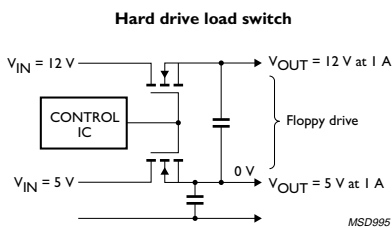
- Low $V_{GS(th)}$ (1.8 V) capability
- Low $R_{DS(on)}$
- Enhanced thermal and electrical properties

Key benefits

- High performance from a small footprint
- Lower power dissipation
- Cooler running applications
- Greater efficiency

Key applications

- Battery-powered motor control
- Load switch in notebook PCs
- High-speed switch in set-top box power supplies
- Driver FET in DC/DC converters



μ TrenchMOS™ part numbering

Philips - Micro
(μ)TrenchMOS™

PMV31XN

Package identifier

N = TSOP6 (SOT457)
W = TSSOP8
V = SOT23
G = SC88 (SOT363)
F = SC70 (SOT323)
R = SC75 (SOT416)
S = SC89 (SOT490)
T = SOT666
Z = MCD

N = N-channel
P = P-channel

Gate level

U = Ultra Low - 8 V_{GS}
X = Extremely Low - 12 V_{GS}
L = Logic level - 15 V_{GS}
E = Enhanced Logic - 20 V_{GS}
S = Standard - 30 V_{GS}

$R_{DS(ON)}$ in m Ω

MSE146

For more information:

- www.semiconductors.philips.com/pip/PMV31XN.html
- www.semiconductors.philips.com/pip/PMV45EN.html
- www.semiconductors.philips.com/pip/PMV56XN.html
- www.semiconductors.philips.com/pip/PMV60EN.html
- www.semiconductors.philips.com/pip/PMV117EN.html
- www.semiconductors.philips.com/pip/PMV213SN.html

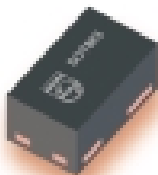
8. Resistor-Equipped Transistors

RET family continues to grow with 81 new options

55 new RETs (or digital transistors) have been released in industry-standard packages – SOT346 (SC-59), SOT323 (SC-70) SOT23 and SOT54 (TO-92) – ensuring maximum design freedom in applications across all market segments, from automotive to communications. Our RETs are also available in an extensive choice of smaller SMD packages and standard Japanese packages, such as SOT416 (SC-75), SOT490 (SC-89), SOT363 (SC-88) and SOT666. In addition, 26 new RETs are offered in the ultra-small SOT883 (SC-101), which has a footprint 90% smaller than SOT23 yet still delivers the same power dissipation and collector current capabilities.

Key features

- Single or dual RETs with a choice of resistor combinations
- Broad range of SMD package options available
- Also available in a leaded package



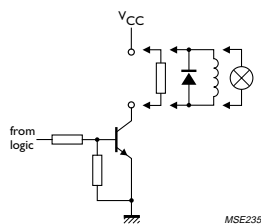
Key benefits

- Increased end-product reliability
- Lower handling and inventory costs
- Simplified circuit design
- Reduced board space requirements
- Shorter assembly times
- Reduced pick and place effort

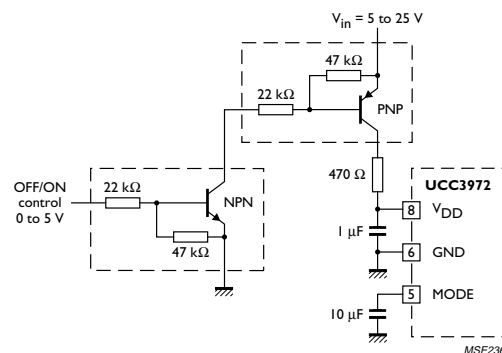
Key applications

- Digital applications
- Switching loads
- Controlling IC inputs

RET to switch loads up to 100 mA



RET to control IC inputs (UCC3972 SMPS controller shown)



For more information:

www.semiconductors.philips.com/selectionguides/tables/30588.html

9. TDA8754

Triple 8-bit ADC

The highly integrated TDA8754 triple 8-bit ADC has extensive functionality built-in including sync processor, flexible PLL (phase lock loop), adjustable clamp level and gain control on each channel, and two separate analog input banks. The device's increased flexibility allows customers to reduce the complexity of their systems, while enabling top-class performance on the whole speed range.

Key features

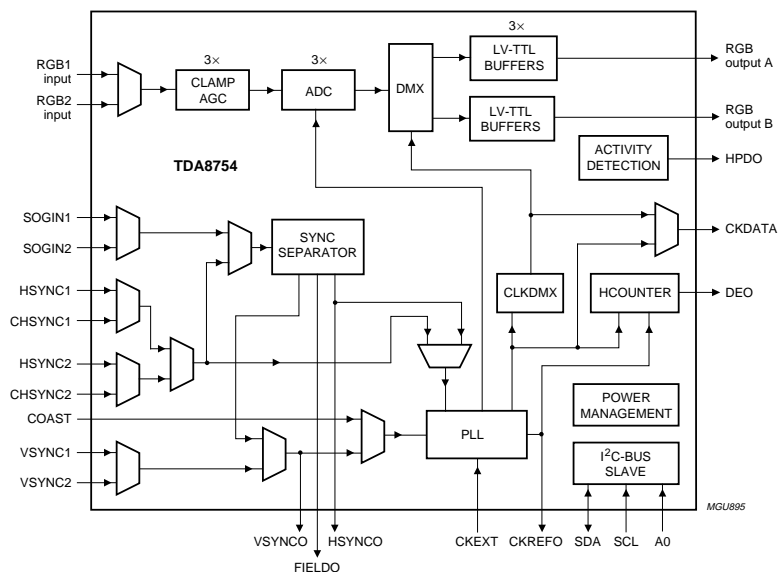
- 2 RGB / YPbPr analog inputs
- Sync separation and processing for sync-on-green
- Composite and 3-level sync
- Flexible PLL with precise phase adjustment and low jitter
- Fully controlled by I²C
- Speed up to 270 Msps

Key benefits

- Reduced system complexity

Key applications

- LCD PC monitors
- Multimedia projectors
- PDP monitors and TVs
- Automotive navigation systems



For more information:

www.semiconductors.philips.com/acrobat/literature/9397/75010456.pdf

New MultiMarket Products List

Comprehensive New Products List Q2 2003

In the following overview you will find all Philips MultiMarket Semiconductors released in the last quarter.

To ensure you can access more information quickly the type numbers are linked directly to their respective Product Information Page (PIP) on the Philips Semiconductors website.

Discretes

Type Number	Description	Package	Type Number	Description	Package
General Application Discretes					
PBSS4240DPN	Double Low $V_{CE(sat)}$ (BISS) 1.5 A, 40 V (NPN/PNP)	SOT457 / SC-74	PDTA143XU	Single PNP RET, R1 = 4.7k, R2 = 10k, 100 mA, 50 V	SOT323 / SC-70
PBSS4240V	Single NPN Low $V_{CE(sat)}$ (BISS) 2 A, 40 V	SOT666	PDTA143ZM	Single PNP RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101
PBSS5240V	Single PNP Low $V_{CE(sat)}$ (BISS) 2 A, 40 V	SOT666	PDTA143ZS	Single PNP RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92
BCP51-10	Single PNP Medium Power Transistor 1 A, 45 V	SOT223 / SC-73	PDTA143ZU	Single PNP RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70
BCP52	Single PNP Medium Power Transistor 1 A, 60 V	SOT223 / SC-73	PDTA144EM	Single PNP RET, R1 = 47k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101
BCP52-10	Single PNP Medium Power Transistor 1 A, 60 V	SOT223 / SC-73	PDTA144WK	Single PNP RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
BCP54-10	Single NPN Medium Power Transistor 1 A, 45 V	SOT223 / SC-73	PDTA144WS	Single PNP RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT54 / TO-92
PUM89	Double RET, R1 = 10 k, R2 = 47 k, 100 mA, 50 V	SOT363 / SC-88	PDTA144WT	Single PNP RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT23
PSS8550C	Single PNP Medium Power Transistor 1 A, 25 V	SOT54 / TO-92	PDTC114EM	Single NPN RET, R1 = 10k, R2 = 10k, 100 mA, 50 V	SOT883 / SC-101
PSS8550D	Single PNP Medium Power Transistor 1 A, 25 V	SOT54 / TO-92	PDTC114TM	Single NPN RET, R1 = 10k, R2 = open, 100 mA, 50 V	SOT883 / SC-101
PSS9014C	Single NPN General Purpose Transistor 0.1 A, 45 V	SOT54 / TO-92	PDTC114YK	Single NPN RET, R1 = 10k, R2 = 47k, 100 mA, 50 V	SOT346 / SC-59
PSS9015B	Single PNP General Purpose Transistor 0.1 A, 45 V	SOT54 / TO-92	PDTA144YM	Single NPN RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101
PMEM4010ND	Ultra low V_f (MEGA) Schottky diode and BISS transistor combination	SOT457 / SC-74	PDTC114YS	Single NPN RET, R1 = 10k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92
PMEM4010PD	Ultra low V_f (MEGA) Schottky diode and BISS transistor combination	SOT457 / SC-74	PDTC123EK	Single NPN RET, R1 = 2.2k, R2 = 2.2k, 100 mA, 50 V	SOT346 / SC-59
BAS16VY	High-speed switching diode array	SOT363 / SC-88	PDTC123ES	Single NPN RET, R1 = 2.2k, R2 = 2.2k, 100 mA, 50 V	SOT54 / TO-92
PSSJ3120CA	Integrated clock terminator	SOT23	PDTA143EU	Single NPN RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70
BZX384 Series	Voltage Regulator Zener Diode	SOD323 / SC-76	PDTC123JK	Single NPN RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT346 / SC-59
BZA856AVL	Quad low capacitance ESD suppressor	SOT353 / SC-88A	PDTC123JM	Single NPN RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101
BZA862AVL	Quad low capacitance ESD suppressor	SOT353 / SC-88A	PDTA123JS	Single NPN RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92
BZA868AVL	Quad low capacitance ESD suppressor	SOT353 / SC-88A	PDTA123JU	Single NPN RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70
BZA956AVL	Quad low capacitance ESD suppressor	SOT665	PDTA123JL	Single NPN RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101
BZA968AVL	Quad low capacitance ESD suppressor	SOT665	PDTA123JS	Single PNP RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92
PDTA114EM	Single PNP RET, R1 = 10k, R2 = 10k, 100 mA, 50 V	SOT883 / SC-101	PDTA123JU	Single PNP RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70
PDTA114TM	Single PNP RET, R1 = 10k, R2 = open, 100 mA, 50 V	SOT883 / SC-101	PDTA124EM	Single PNP RET, R1 = 22k, R2 = 22k, 100 mA, 50 V	SOT883 / SC-101
PDTA114YK	Single PNP RET, R1 = 10k, R2 = 47k, 100 mA, 50 V	SOT346 / SC-59	PDTA124TK	Single NPN RET, R1 = 22k, R2 = open, 100 mA, 50 V	SOT346 / SC-59
PDTA114YM	Single PNP RET, R1 = 10k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101	PDTA124TM	Single NPN RET, R1 = 22k, R2 = open, 100 mA, 50 V	SOT883 / SC-101
PDTA114YS	Single PNP RET, R1 = 10k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92	PDTA124TS	Single NPN RET, R1 = 22k, R2 = open, 100 mA, 50 V	SOT54 / TO-92
PDTA114YU	Single PNP RET, R1 = 10k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70	PDTA124TT	Single NPN RET, R1 = 22k, R2 = open, 100 mA, 50 V	SOT23
PDTA123EK	Single PNP RET, R1 = 2.2k, R2 = 2.2k, 100 mA, 50 V	SOT346 / SC-59	PDTA124TU	Single NPN RET, R1 = 22k, R2 = open, 100 mA, 50 V	SOT323 / SC-70
PDTA123ES	Single PNP RET, R1 = 2.2k, R2 = 2.2k, 100 mA, 50 V	SOT54 / TO-92	PDTA124XK	Single NPN RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT346 / SC-59
PDTA123EJ	Single PNP RET, R1 = 2.2k, R2 = 2.2k, 100 mA, 50 V	SOT323 / SC-70	PDTA124XM	Single NPN RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101
PDTA123JK	Single PNP RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT346 / SC-59	PDTA124XS	Single NPN RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92
PDTA123JM	Single PNP RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101	PDTA124XT	Single NPN RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT23
PDTA123JS	Single PNP RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92	PDTA124XU	Single NPN RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70
PDTA123JU	Single PNP RET, R1 = 2.2k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70	PDTA143EM	Single NPN RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101
PDTA124EM	Single PNP RET, R1 = 22k, R2 = 22k, 100 mA, 50 V	SOT883 / SC-101	PDTA143TK	Single NPN RET, R1 = 4.7k, R2 = open, 100 mA, 50 V	SOT346 / SC-59
PDTA124XK	Single PNP RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT346 / SC-59	PDTA143TM	Single NPN RET, R1 = 4.7k, R2 = open, 100 mA, 50 V	SOT54 / TO-92
PDTA124XM	Single PNP RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101	PDTA143TU	Single NPN RET, R1 = 4.7k, R2 = open, 100 mA, 50 V	SOT323 / SC-70
PDTA124XS	Single PNP RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92	PDTA143XU	Single NPN RET, R1 = 4.7k, R2 = 10k, 100 mA, 50 V	SOT883 / SC-101
PDTA124XT	Single PNP RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT23	PDTA143ZM	Single NPN RET, R1 = 4.7k, R2 = 10k, 100 mA, 50 V	SOT54 / TO-92
PDTA124XU	Single PNP RET, R1 = 22k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70	PDTA143ZS	Single NPN RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70
PDTA143EM	Single PNP RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101	PDTA143ZU	Single NPN RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70
PDTA143TK	Single PNP RET, R1 = 4.7k, R2 = open, 100 mA, 50 V	SOT346 / SC-59	PDTA144EM	Single NPN RET, R1 = 47k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101
PDTA143TM	Single PNP RET, R1 = 4.7k, R2 = open, 100 mA, 50 V	SOT346 / SC-59	PDTA144WK	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT346 / SC-59
PDTA143TS	Single NPN RET, R1 = 4.7k, R2 = open, 100 mA, 50 V	SOT54 / TO-92	PDTA144WS	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT54 / TO-92
PDTA143TT	Single PNP RET, R1 = 4.7k, R2 = open, 100 mA, 50 V	SOT23	PDTA144WT	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT23
PDTA143TU	Single PNP RET, R1 = 4.7k, R2 = open, 100 mA, 50 V	SOT323 / SC-70	PDTA144YK	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT323 / SC-70
PDTA143XU	Single NPN RET, R1 = 4.7k, R2 = 10k, 100 mA, 50 V	SOT54 / TO-92	PDTA144YS	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA143ZM	Single NPN RET, R1 = 4.7k, R2 = 10k, 100 mA, 50 V	SOT54 / TO-92	PDTA144YU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT883 / SC-101
PDTA143ZS	Single NPN RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT54 / TO-92	PDTA144YM	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT54 / TO-92
PDTA143ZU	Single NPN RET, R1 = 4.7k, R2 = 47k, 100 mA, 50 V	SOT323 / SC-70	PDTA144YU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT54 / TO-92
PDTA144EM	Single NPN RET, R1 = 47k, R2 = 47k, 100 mA, 50 V	SOT883 / SC-101	PDTA144YS	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT54 / TO-92
PDTA144WK	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT346 / SC-59	PDTA144ZM	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT883 / SC-101
PDTA144WS	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT54 / TO-92	PDTA144ZS	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT323 / SC-70
PDTA144WT	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT23	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT323 / SC-70
PDTA144YK	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT346 / SC-59	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA144YS	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT54 / TO-92	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA144YU	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT323 / SC-70	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA144YM	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT883 / SC-101	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA144YU	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT54 / TO-92	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA144YS	Single NPN RET, R1 = 47k, R2 = open, 100 mA, 50 V	SOT323 / SC-70	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA144ZM	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT883 / SC-101	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA144ZS	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT54 / TO-92	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59
PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT323 / SC-70	PDTA144ZU	Single NPN RET, R1 = 47k, R2 = 22k, 100 mA, 50 V	SOT346 / SC-59

New MultiMarket Products List

Type Number	Description	Package
Power Discretes		
PMWD15UN	µTrenchMOS - 20 V N-Channel MOSFET	TSSOP8
PMWD18UN	µTrenchMOS - 30 V N-Channel MOSFET	TSSOP8
PMGD8000LN	µTrenchMOS - 30 V N-Channel dual MOSFET	SC-88 (SOT363)
PMN34UN	µTrenchMOS - 30 V N-Channel MOSFET	TSOP6 (SOT457)
PHU101NQ03LT	30 V N-Channel MOSFET	IPAK (SOT533)
BUK1M200-50SDL	Quad Channel TOPFET	SOT163-1 (SO20)
BUK1M200-50SGTD	Quad Channel TOPFET	SOT163-1 (SO20)
PH8230E	30 V N-Channel MOSFET	LFPAK (SOT669)
PH3230S	30 V N-Channel MOSFET	LFPAK (SOT669)
PMV2135N	µTrenchMOS - 100 V N-Channel MOSFET	SOT23
PMV117EN	µTrenchMOS - 30 V N-Channel MOSFET	SOT23
PMV60EN	µTrenchMOS - 30 V N-Channel MOSFET	SOT23
PMV45EN	µTrenchMOS - 30 V N-Channel MOSFET	SOT23
PMV56XN	µTrenchMOS - 20 V N-Channel MOSFET	SOT23
PMV31XN	µTrenchMOS - 20 V N-Channel MOSFET	SOT23
BUK75/7606-55B	55 V High Performance Automotive MOSFET	BUK7506-55B in SOT78 (TO220AB)
BUK75/7607-30B	30 V High Performance Automotive MOSFET	BUK7606-55B in SOT404 (D ² PAK)
BUK95/964R4-40B	40 V High Performance Automotive MOSFET	BUK7507-30B in SOT78 (TO220AB)
		BUK7607-30B in SOT404 (D ² PAK)
		BUK954R4-40B in SOT78 (TO220AB)
		BUK964R4-40B in SOT404 (D ² PAK)

Logic

Type Number	Description	Package
GTL2000	22-bit GTL Processor Voltage Clamp	DGG
GTL2010	10-bit GTL Processor Voltage Clamp	BS
PCA9564	Parallel Bus to I ² C Bus Controller	D, PW
PCK12429	25-400 MHz Differential PECL Clock Generator	BD
PCKEP14	2.5 V / 3.3 V 1:5 Differential ECL/PECL/HSTL Clock Driver	D
74HC2G00	5 V Dual 2-Input NAND Gate	DP
74HC2G02	5 V Dual 2-Input NOR Gate	DP
74HC2G08	5 V Dual 2-Input AND Gate	DP
74HC2G32	5 V Dual 2-Input OR Gate	DP
74HC2G86	5 V Dual 2-Input EXCLUSIVE-OR Gate	DP
74HC3G04	5 V Triple Inverter	DP
74HC3G14	5 V Triple Inverting Schmitt Trigger	DP
74HC3G34	5 V Triple Buffer Gate	DP
74HCT2G00	5 V Dual 2-Input NAND Gate	DP
74HCT2G02	5 V Dual 2-Input NOR Gate	DP
74HCT2G32	5 V Dual 2-Input OR Gate	DP
74HCT2G86	5 V Dual 2-Input EXCLUSIVE-OR Gate	DP
74HCT3G04	5 V Triple Inverter	DP
74HCT3G34	5 V Triple Buffer Gate	DP

Type Number	Description	Package
DIGITAL DATACOM PRODUCTS		
SC16C554IB80	Quad Channel Universal Asynchronous Receiver Transmitter with 16-Byte FIFOs and Infrared (IrDA) Encoder/Decoder; IMPACT Series	B, A
SC16C754IA68	Quad Channel Universal Asynchronous Receiver Transmitter with 64-Byte FIFOs	A
SCC2691AC1D24	5 V 1-Channel UART; Intel Interface; CMOS; 4-Byte FIFOs	D

Standard Analog

Type Number	Description	Package
LP2985A-xxUK or D	Very low noise, low drop out, 150 mA linear regulator using a CMOS process technology.	CSP (Chip Scale Packaging) and SOT23-5
SA57000-xxUK	CapFREE 150 mA, low noise, low drop out regulator with thermal protection.	CSP (Chip Scale Packaging)
MAX8877-xx	Very low noise, low drop out, 150 mA linear regulator using a CMOS process technology	SOT23-5 CSP (Chip Scale Packaging)
MAX8878-xx	Very low noise, low drop out, 150 mA linear regulator using a CMOS process technology.	SOT23-5 CSP (Chip Scale Packaging)
MAX810xW	Single function microprocessor reset used to monitor supply voltages in microprocessor and other logic systems.	SOT323 / SC-70
MAX809xW	Single function microprocessor reset used to monitor supply voltages in microprocessor and other logic systems.	SOT323 / SC-70
MAX63xx Family TDA8769	Ultra-low power microprocessor reset circuit	SOT323 / SC-70
TDA8769	12-bit, 80/105 Msps analog-to-digital converter (ADC)	HTQFP48
TDA9965	Nyquist/High IF sampling	LQFP48
TDA9965A	12-bit, 5.0 V, 30 Msps analog-to-digital interface for CCD cameras	LQFP48
NE57810	12-bit, 5.0 V, 40 Msps analog-to-digital interface for CCD cameras	LQFP48
NE57811	Advanced DDR termination regulators	SPAK-5 (SOT756)
TDA8754	Advanced DDR termination regulators	SPAK-5 (SOT756)
	Triple 8-bit ADC	LQFP144

Microcontrollers

Type Number	Description	Package
LPC2104 , LPC2105 , LPC2106	Single-chip 32-bit microcontrollers	LQFP48

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SCS 76

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